

RoHS

COMPLIANT **HALOGEN**

FREE

Hyperfast Rectifier, 8 A FRED Pt®



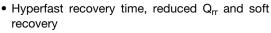


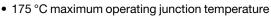
TO-252AA (D-PAK)

	1	
0 1 N/C		3 O Anode

PRODUCT SUMMARY					
Package	TO-252AA (D-PAK)				
I _{F(AV)}	8 A				
V _R	600 V				
V _F at I _F	1.3 V				
t _{rr} (typ.)	18 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES





- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V_{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 143 °C	8		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	90	Α	
Peak repetitive forward current	I _{FM}	T _C = 143 °C, f = 20 kHz, d = 50 %	16		
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ		-	-	
Forward voltage V _F	V	I _F = 8 A	-	2.0	2.4	V
	٧F	I _F = 8 A, T _J = 150 °C	-	1.3	1.8	
Doverno lockogo overent		$V_R = V_R$ rated	-	-	50	
Reverse leakage current I _R		T _J = 150 °C, V _R = V _R rated	-	-	500	μA
Junction capacitance	C _T	V _R = 600 V	-	8	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8 -		-	nH	





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time t _{rr}	$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			21			
	+	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	18	22	
	۲rr	T _J = 25 °C	$I_F = 8 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	25	-	ns
		T _J = 125 °C		-	34	-	
Peak recovery current I _{RRI}	1	T _J = 25 °C		-	3.3	-	Α
	IRRM	T _J = 125 °C		-	4.8	-] ^
Reverse recovery charge	0	T _J = 25 °C		-	39	-	nC
	Q _{rr}	T _J = 125 °C		-	90	-	IIC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	1.8	2.2	°C/W
Approximate weight				0.3		g
Approximate weight				0.01		oz.
Marking device		Case style TO-252AA (D-PAK)		8EWH	06FNH	

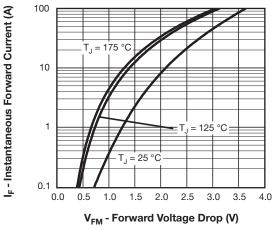


Fig. 1 - Typical Forward Voltage Drop Characteristics

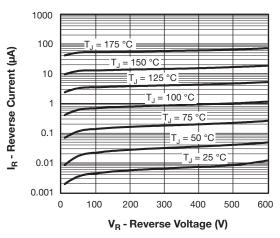


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

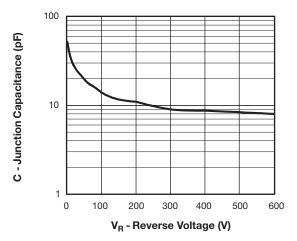


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

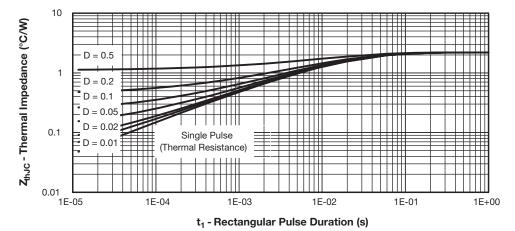


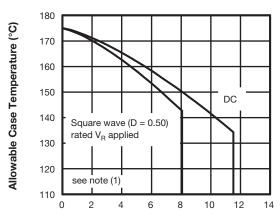
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





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 $I_{F(AV)}$ - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

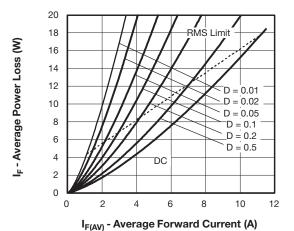


Fig. 6 - Forward Power Loss Characteristics

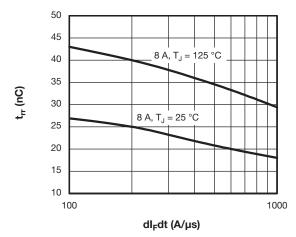


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

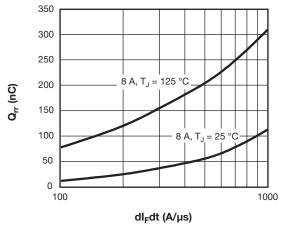


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = \text{Rated } V_R \\ \end{array}$

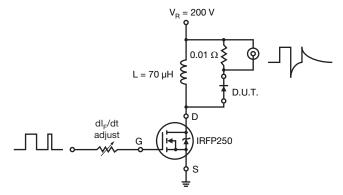
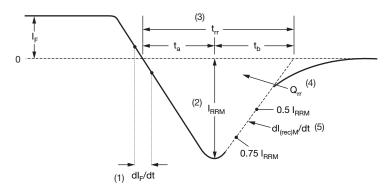


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

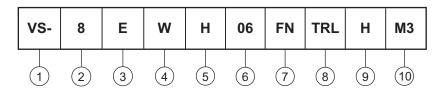
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (8 = 8 A)

Gircuit configuration:

E = single diode

Package identifier:

W = D-PAK

5 - H = hyperfast recovery

Voltage rating (06 = 600 V)

7 - FN = TO-252AA

None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - H = AEC-Q101 qualified

10 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-8EWH06FNHM3	75	3000	Antistatic plastic tube		
VS-8EWH06FNTRHM3	2000	2000	13" diameter reel		
VS-8EWH06FNTRRHM3	3000	3000	13" diameter reel		
VS-8EWH06FNTRLHM3	3000	3000	13" diameter reel		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95519</u>				
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			



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